

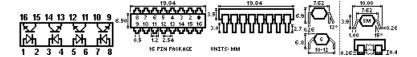
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# ISQ202: OPTICALLY COUPLED ISOLATORS

#### Circuit



#### **Features**

5000 V Isolation. High Current Transfer Ratio (125% to 250%). Low Cost Dual-In-Line Package. Quad Configuration.

#### Description

The ISQ202 is an optically coupled isolator. Each channel consists of a Gallium Arsenide infrared emitting diode and an NPN silicon phototransistor mounted in a standard 16-pin dual-in-line package. Surface Mount Option Available.

The ISQ202 offers four channels per unit.

All electrical parameters are 100% tested by manufacturing. Specifications are guaranteed to a cumulative 0.65% AQL.

## Absolute Maximum Ratings (Ta=25 °C)

Storage Temperature:  $-55\,^{\circ}$ C to  $+150\,^{\circ}$ C Operating Temperature:  $-55\,^{\circ}$ C to  $+100\,^{\circ}$ C

Lead Soldering: 260 °C for 10s, 1.6mm from case

Input-to-Output Isolation Voltage: ±5000Vdc (note 1)

#### **Input Diode**

Forward DC Current: 60mA Reverse DC Voltage: 3V

Peak Forward Current: 1A (PW.=100µs, duty ratio 0.001)

Power Dissipation: 100mW

Derate Linearly: 1.33mW/°C above 25 °C

## **Output Transistor**

Collector-Emitter Voltage: 30V Emitter-Collector Voltage: 7V Power Dissipation: 150mW

Derate Linearly: 2.00mW/℃ above 25℃

Package

Total Power Dissipation: 500mW

Derate Linearly: 6.67mW/℃ above 25℃

# **Electro-optical Characteristics (Ta=25℃)**

INPUT	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> =20mA		1.2	1.5	V
		I <sub>F</sub> =1mA		1	1.2	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> =3V			10	μΑ
OUTPUT						
H <sub>FE</sub>		$I_C = 100 \mu A, V_{CE} = 5 V$	100	200		
BV <sub>CEO</sub>	Collector-Emitter Voltage	I <sub>C</sub> =1mA	30			V
BV <sub>ECO</sub>	Emitter-Collector Voltage	I <sub>E</sub> =0.1mA	7			V
I <sub>CEO</sub>	Collector-Emitter Dark Current	V <sub>CE</sub> =10V			50	nA
COUPLED						
CTR	DC Current Transfer Ratio	I <sub>F</sub> =10mA, V <sub>CE</sub> =10V	125		250	%
		I <sub>F</sub> =1mA, I <sub>C</sub> =10V	30	50		%
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage	I <sub>F</sub> =10mA, I <sub>C</sub> =2mA		0.2	0.4	V
C <sub>F</sub>	Floating Capacitance	V=0, f=1MHz		0.6	1	pf
	Input-Output Isolation Resistance	V <sub>IO</sub> =500V (Note 1)	5x10			ohm

## Notes

1. Measured with input leads shorted together and output leads shorted together.

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